

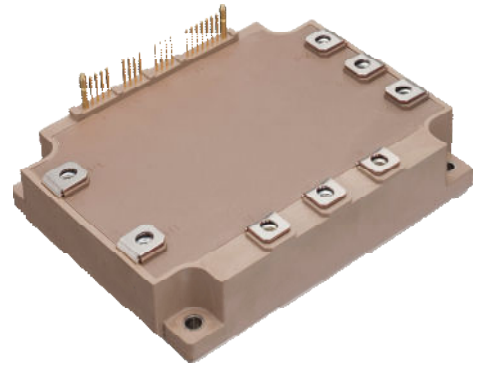
7MBP300XEN065-50

IGBT Modules

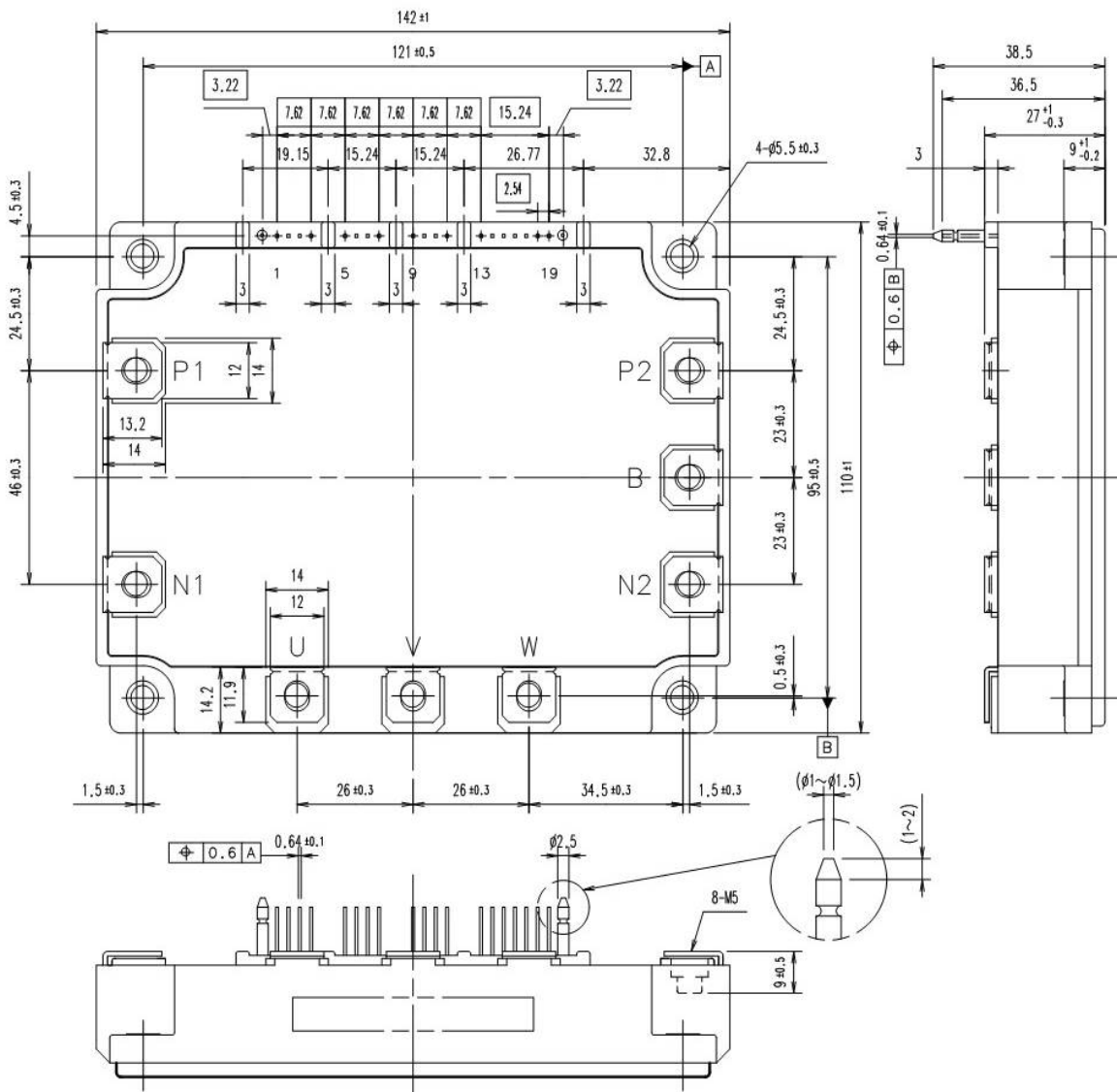
IGBT Module (X series)
650V / 300A / IPM

■ Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



■ Outline drawing (Unit : mm)



Weight : 940g(typ.)

7MBP300XEN065-50

IGBT Modules

Absolute maximum ratings

 $T_C = 25^{\circ}\text{C}$, $T_{vj} = 25^{\circ}\text{C}$, $V_{CC} = 15\text{V}$ unless otherwise specified

Items		Symbol	Conditions	Min.	Max.	Units
Collector-Emitter voltage		V_{CES}	*1	-	650	V
Short circuit voltage		V_{SC}	*2	200	400	V
Inverter	Collector current	I_C	DC	-	300	A
		I_{CP}	1ms	-	600	A
		$-I_C$	Duty=100% *3	-	300	A
	Total power dissipation	P_{tot}	IGBT 1 device *4	-	1119	W
Brake	Repetitive peak reverse voltage	V_{RRM}	Diode part	-	650	V
	Collector current	I_C	DC	-	150	A
		I_{CP}	1ms	-	300	A
	Forward current of diode	I_F		-	150	A
Total power dissipation		P_{tot}	IGBT 1 device *4	-	684	W
Supply voltage of pre-driver		V_{CC}	*5	-0.5	20	V
Input signal voltage		V_{in}	*6	-0.5	$V_{CC} + 0.5$	V
Alarm signal voltage		V_{ALM}	*7	-0.5	V_{CC}	V
Alarm signal current		I_{ALM}	*8	-	20	mA
Virtual junction temperature		T_{vj}		-	175	$^{\circ}\text{C}$
Operating virtual junction temperature		T_{vjop}		-	150	$^{\circ}\text{C}$
Operating case temperature		T_c		-20	125	$^{\circ}\text{C}$
Storage temperature		T_{stg}		-40	125	$^{\circ}\text{C}$
Solder temperature		T_{sol}	*9	-	260	$^{\circ}\text{C}$
Isolating voltage		V_{isol}	*10	-	2500	Vrms
Mounting torque of screws to heat sink		M_s	Mounting(M5)	2.5	3.5	Nm
Mounting torque of screws to terminals		M_t	Main terminals(M5)	2.5	3.5	Nm

Notes

*1: V_{CES} shall be applied to the input voltage between all Collector and Emitter.

[P1-(U,V,W) , P2-(U,V,W) , (U,V,W,B)-N1 , (U,V,W,B)-N2]

*2: In the case of the load inductance to be over 1 μH .

*3: Duty=150 $^{\circ}\text{C}/R_{th(j-c)D}/(I_F \times V_F \text{ Max.}) \times 100$

*4: $P_{tot}=150^{\circ}\text{C}/R_{th(j-c)Q}$

*5: V_{CC} shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9, 14 and 13.

*6: V_{in} shall be applied to the input voltage between terminal No.2 and 1, 6 and 5, 10 and 9, 15~18 and 13.

*7: V_{ALM} shall be applied to the voltage between terminal No.4 and 1, 8 and 5, 12 and 9, 19 and 13.

*8: I_{ALM} shall be applied to the input current to terminal No.4, 8, 12 and 19.

*9: Immersion time 10 $\pm$ 1sec. 1 time.

*10: Terminal to base, 50/60Hz sine wave 1 min. All terminals should be connected together during the test.

7MBP300XEN065-50

IGBT Modules

■ Electrical characteristics

● Main circuit

 $T_{vj}=25^{\circ}\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item	Symbol	Conditions	Min.	Typ.	Max.	Units
Inverter	Collector current at off signal input	I_{CES} $V_{CE} = 650\text{V}$	-	-	1.0	mA
	Collector-Emmitter saturation voltage *11	$V_{CE(sat)}$ $I_C = 300\text{A}$	-	-	1.65	V
	Forward voltage of FWD *11	V_F $I_F = 300\text{A}$	-	-	2.20	V
Brake	Collector current at off signal input	I_{CES} $V_{CE} = 650\text{V}$	-	-	1.0	mA
	Reverse current	I_{RRM} $V_R = 650\text{V}$	-	-	1.0	mA
	Collector-Emmitter saturation voltage *11	$V_{CE(sat)}$ $I_C = 150\text{A}$	-	-	1.50	V
	Forward voltage of FWD *11	V_F $I_F = 150\text{A}$	-	-	2.20	V
Switching time *12	t_{on}	$I_C = 300\text{A}$ $T_{vj} = 150^{\circ}\text{C}$	0.5	-	-	μs
	$t_{d(on)}$		0.5	-	-	μs
	t_{off}	$V_{DC} = 300\text{V}$	-	-	2.0	μs
	$t_{d(off)}$		-	-	1.7	μs
	t_{tr}	$I_F = 300\text{A}$ $T_{vj} = 150^{\circ}\text{C}$	-	-	0.5	μs

*11: The Max value is a case where it measures from P2-(U,V,W,B) , (U,V,W,B)-N2.

*12: Turn on time (t_{on}) = $t_{d(on)} + t_r$, Turn off time (t_{off}) = $t_{d(off)} + t_f$

● Control circuit

 $T_{vj}=25^{\circ}\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item	Symbol	Conditions	Min.	Typ.	Max.	Units
Supply current of P-side pre-driver (per one unit)	I_{cpp}	Switching frequency (f_{SW}) = 0~15kHz $T_C = -20 \sim 125^{\circ}\text{C}$	-	-	34	mA
Supply current of N-side pre-driver	I_{ccn}		-	-	122	mA
Input signal threshold voltage	$V_{in(th)(on)}$	$V_{in}\text{-GND}$	1.2	1.4	1.6	V
	$V_{in(th)(off)}$		1.5	1.7	1.9	V

● Protection circuit

 $T_{vj}=25^{\circ}\text{C}$, $V_{CC}=15\text{V}$ unless otherwise specified

Item	Symbol	Conditions	Min.	Typ.	Max.	Units
Over current protection level	I_{OC}	$T_{vj}=150^{\circ}\text{C}$	450	-	-	A
		Resistance load	225	-	-	A
Over current protection delay time	t_{dOC}	$T_{vj}=150^{\circ}\text{C}$	-	4.0	-	μs
Short circuit protection delay time	t_{dSC}	$T_{vj}=150^{\circ}\text{C}$	-	1.0	-	μs
IGBT chips over heating protection temperature level	T_{JOH}	Surface of IGBT chips	175	-	-	$^{\circ}\text{C}$
Over heating protection hysteresis	T_{jH}		-	20	-	$^{\circ}\text{C}$
Under voltage protection level	V_{UV}		11.0	-	12.5	V
Under voltage protection hysteresis	V_H		0.2	0.5	-	V
Alarm signal hold time	$t_{ALM(OC)}$	ALM-GND	1.0	2.0	2.4	ms
	$t_{ALM(UV)}$	$T_C = -20 \sim 125^{\circ}\text{C}$ $V_{CC} \geq 10\text{V}$	3.5	4.0	4.5	ms
	$t_{ALM(TJOH)}$		7.0	8.0	9.0	ms
Alarm signal voltage	V_{ALMH}	ALM-GND, without protection	14.5	-	15.0	V
Resistance for current limit	R_{ALM}		960	-	1570	Ω

7MBP300XEN065-50

IGBT Modules

■ Thermal resistance characteristics ($T_c = 25^\circ\text{C}$)

Item			Symbol	Min.	Typ.	Max.	Units
Thermal resistance junction to case *13	Inverter	IGBT	$R_{th(j-c)Q}$	-	-	0.134	K/W
		FWD	$R_{th(j-c)D}$	-	-	0.191	K/W
	Brake	IGBT	$R_{th(j-c)Q}$	-	-	0.219	K/W
		FWD	$R_{th(j-c)D}$	-	-	0.404	K/W
Thermal resistance case to heat sink *14			$R_{th(c-s)}$	-	0.05	-	K/W

*13: For 1 device, the measurement point of the case is just under the chip.

*14: This is the value which is defined mounting on the additional heat sink with 1 W/(m·K) thermal grease.

■ Noise immunity ($V_{DC}=300\text{V}$, $V_{CC}=15\text{V}$)

Item	Conditions	Min.	Typ.	Max.	Units
Common mode rectangular noise	Pulse width 1 μs , polarity $\pm$, 10min. Judge: no over-current, no miss operating	± 2.0	-	-	kV

■ Recommended operating conditions

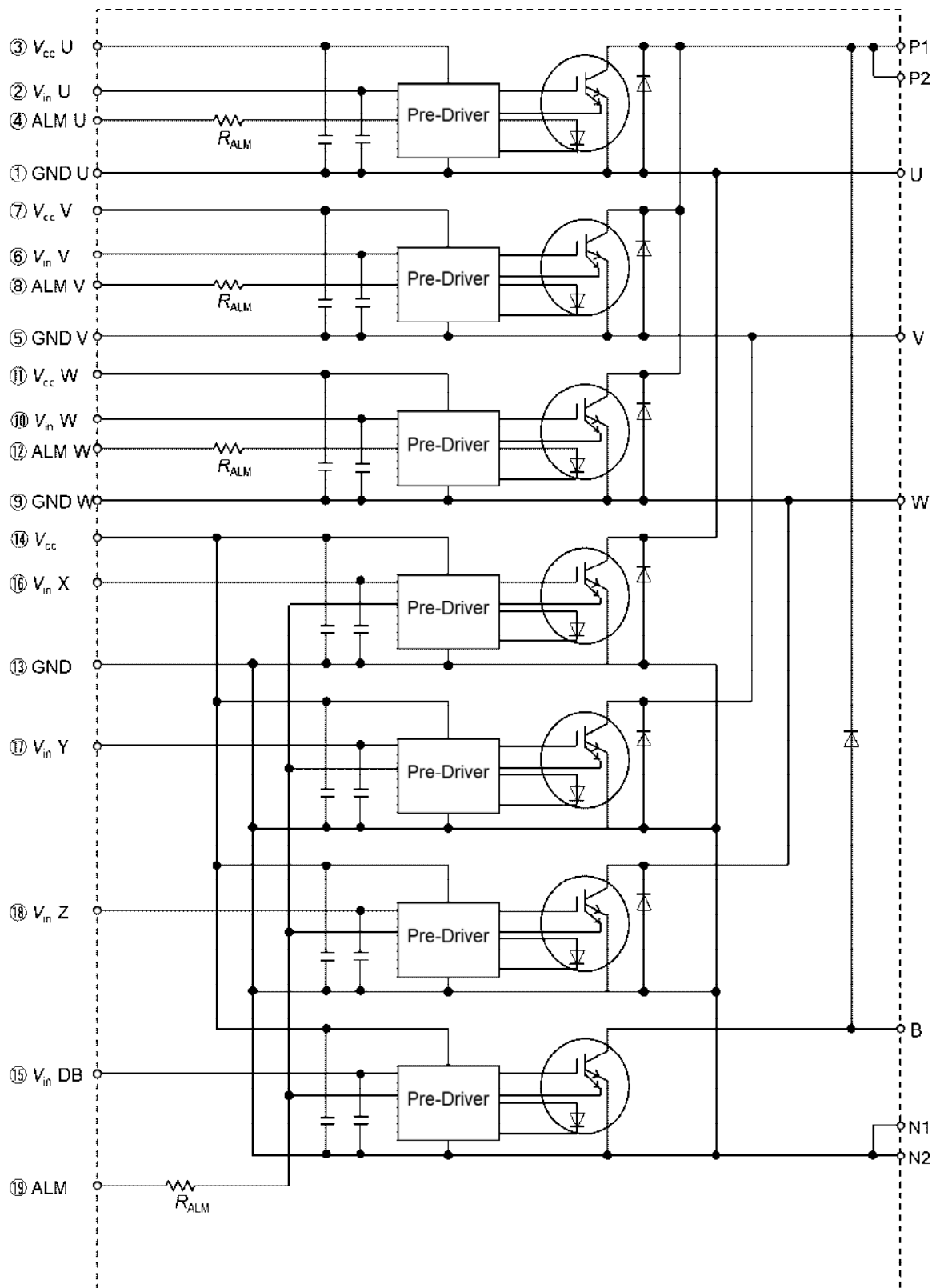
Item	Symbol	Min.	Typ.	Max.	Units
DC bus voltage	V_{DC}	-	-	400	V
Power supply voltage of pre-driver	V_{CC}	13.5	15.0	16.5	V
Switching frequency of IPM	f_{SW}	-	-	20.0	kHz
Arm short through blocking time for IPM's input signal *15	t_{dead}	1.5	-	-	μs
Screw torque (M5)	-	2.5	-	3.5	Nm

*15: $t_{dead} = t_{off} - t_{d(on)}$

7MBP300XEN065-50

IGBT Modules

■ Block diagram



Pre-drivers include following functions

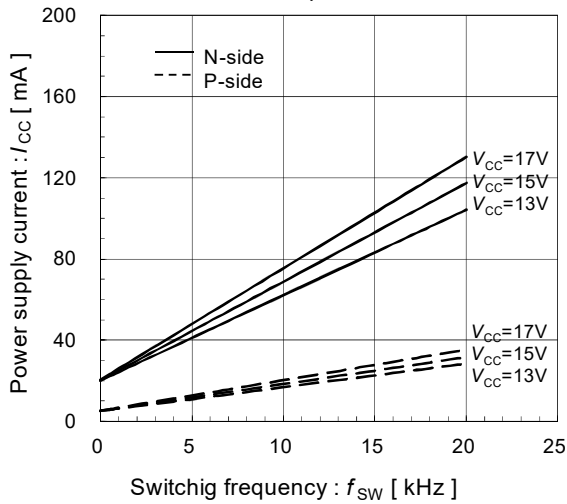
1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

7MBP300XEN065-50

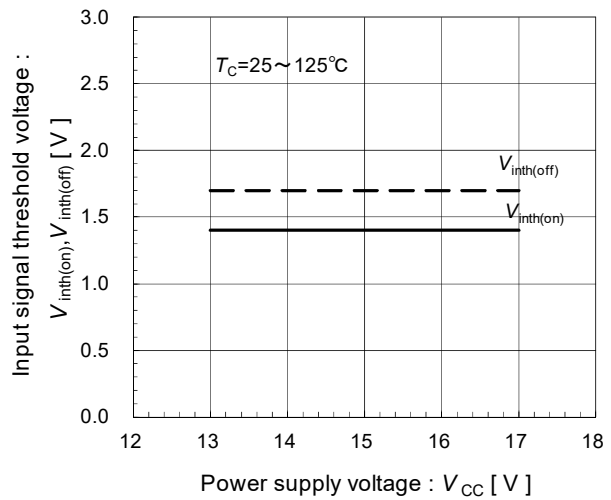
IGBT Modules

■ Characteristics (representative) ● Control circuit

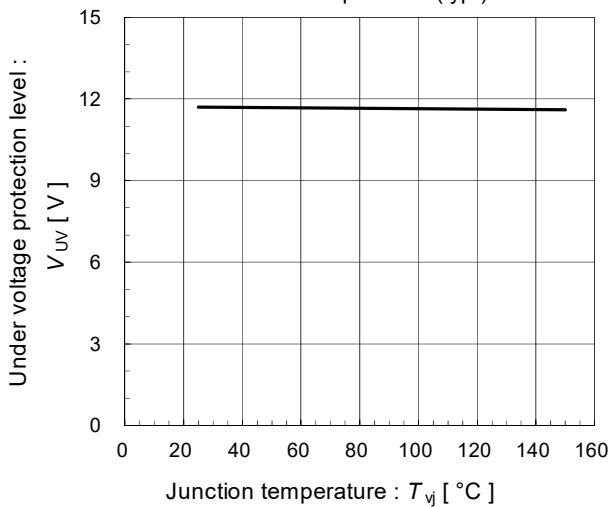
Power supply current vs. Switching frequency (typ.)
 $T_{vj} = 25^\circ\text{C}$



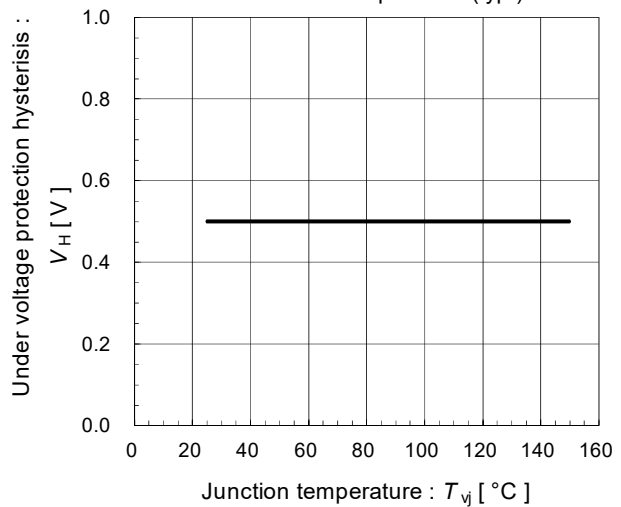
Input signal threshold voltage
vs. Power supply voltage (typ.)



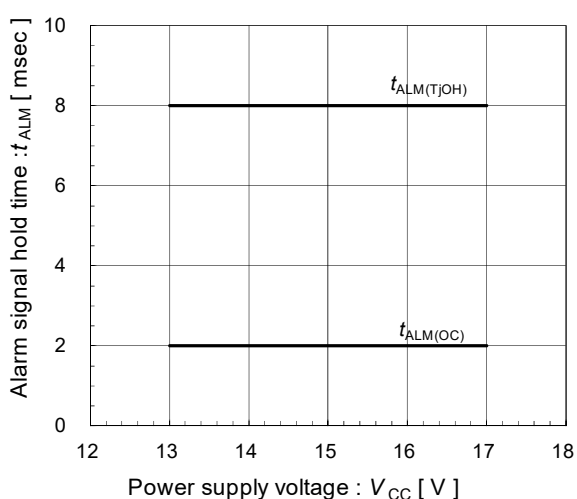
Under voltage protection level
vs. Junction temperature (typ.)



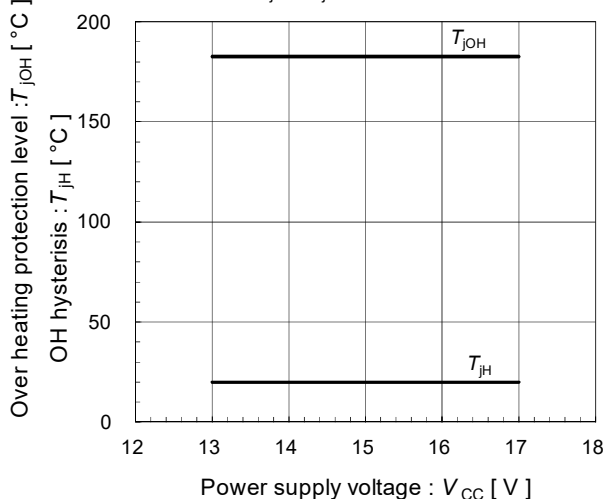
Under voltage protection hysteresis
vs. Junction temperature (typ.)



Alarm signal hold time
vs. Power supply voltage (typ.)



Over heating characteristics
 T_{jOH}, T_{jH} vs. V_{CC} (typ.)

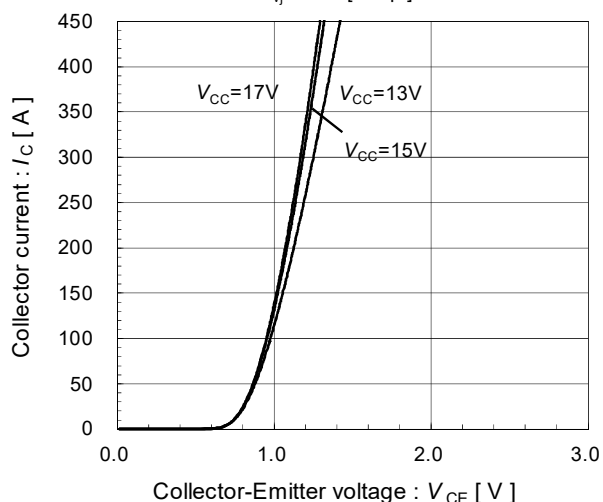


7MBP300XEN065-50

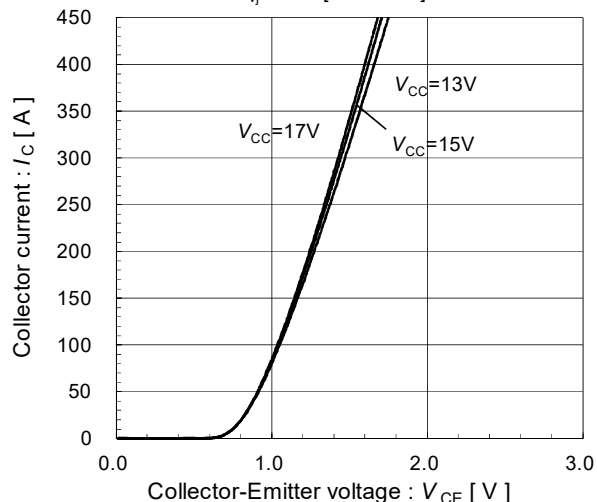
IGBT Modules

● Inverter

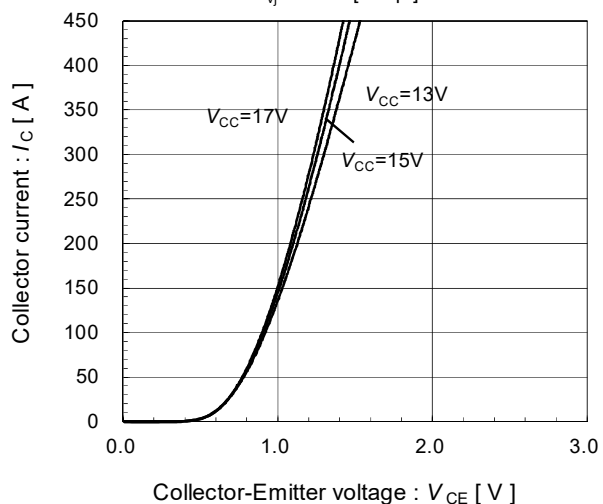
Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=25^{\circ}\text{C}$ [Chip]



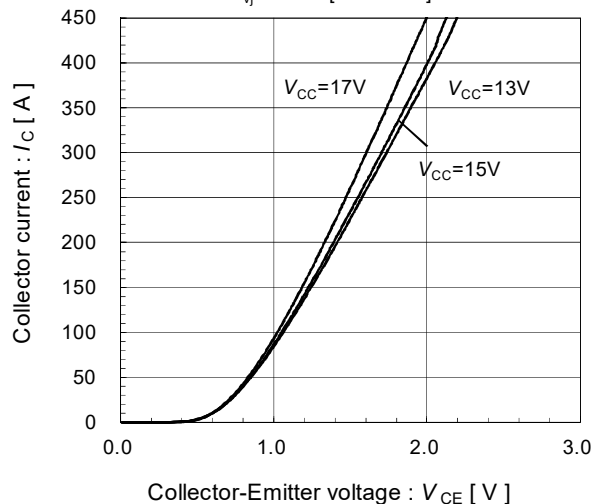
Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=25^{\circ}\text{C}$ [Terminal]



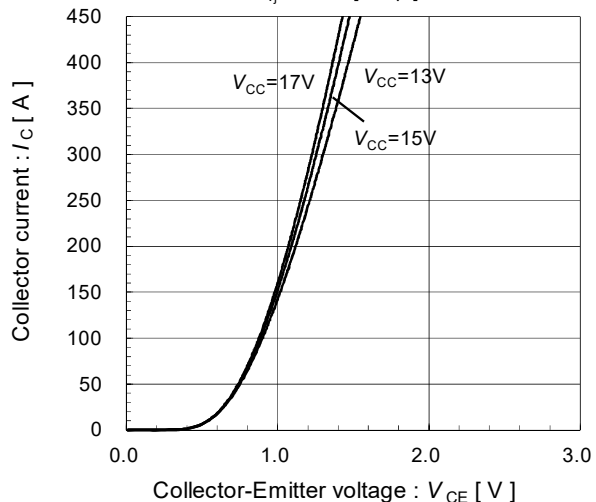
Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=125^{\circ}\text{C}$ [Chip]



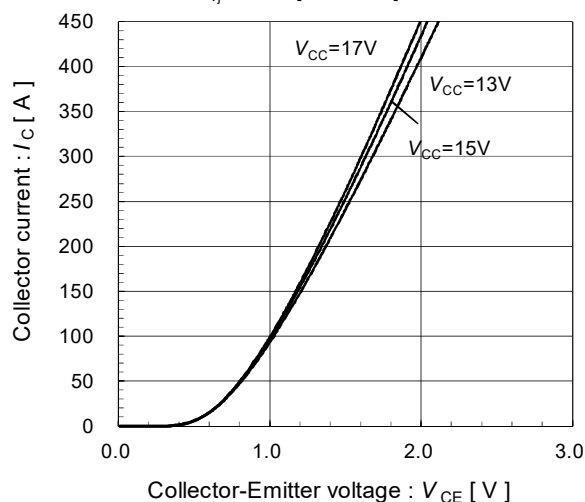
Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=125^{\circ}\text{C}$ [Terminal]



Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=150^{\circ}\text{C}$ [Chip]

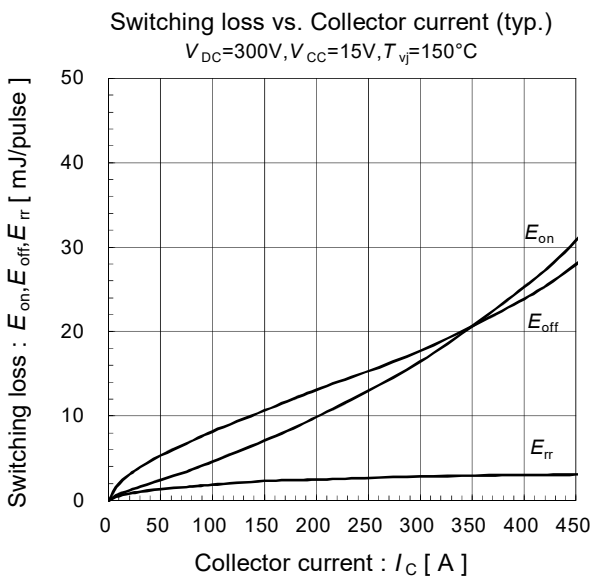
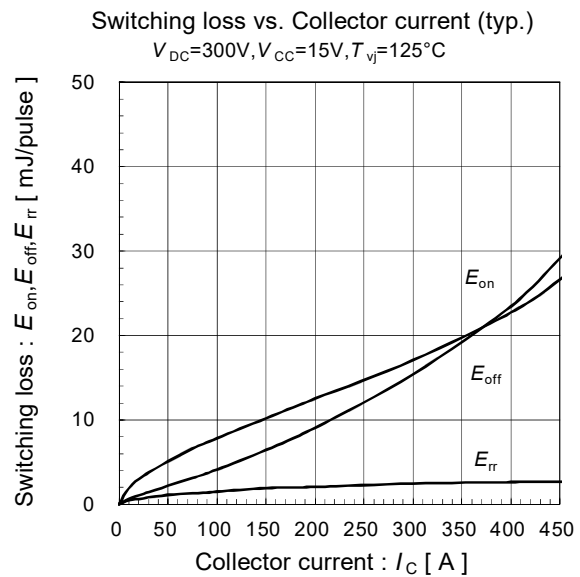
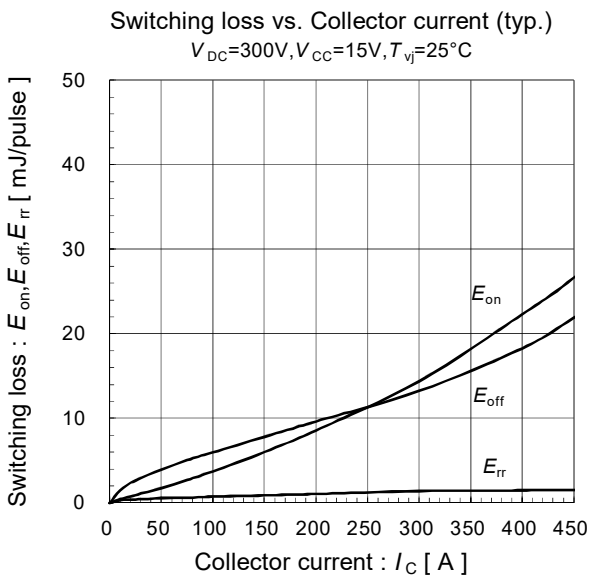
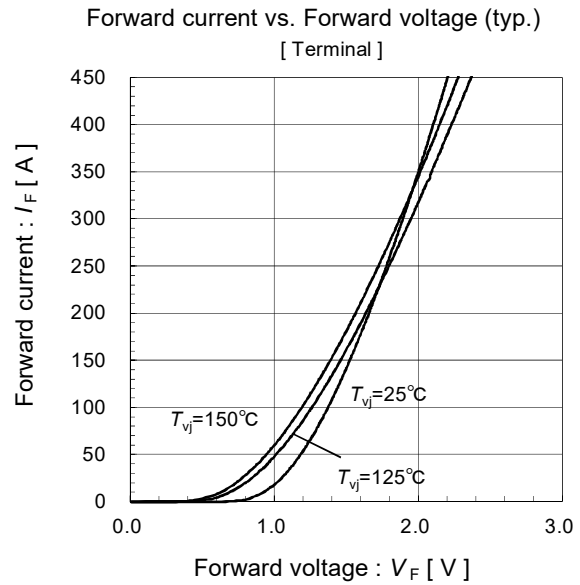
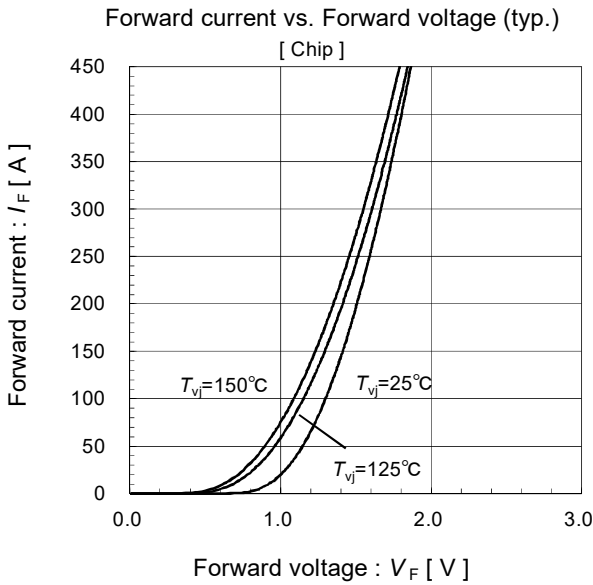


Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=150^{\circ}\text{C}$ [Terminal]



7MBP300XEN065-50

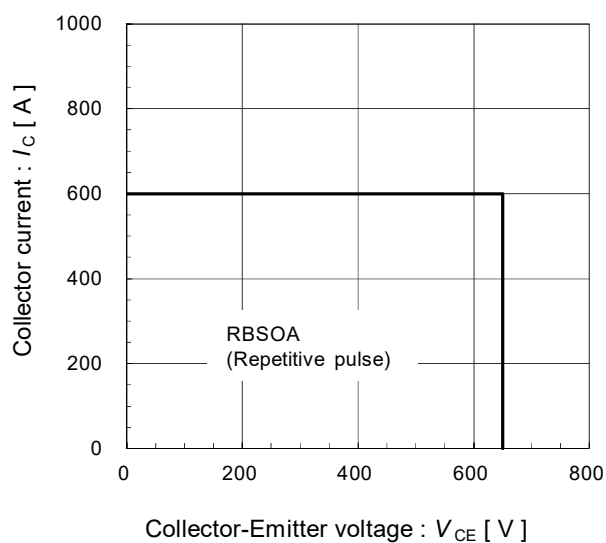
IGBT Modules



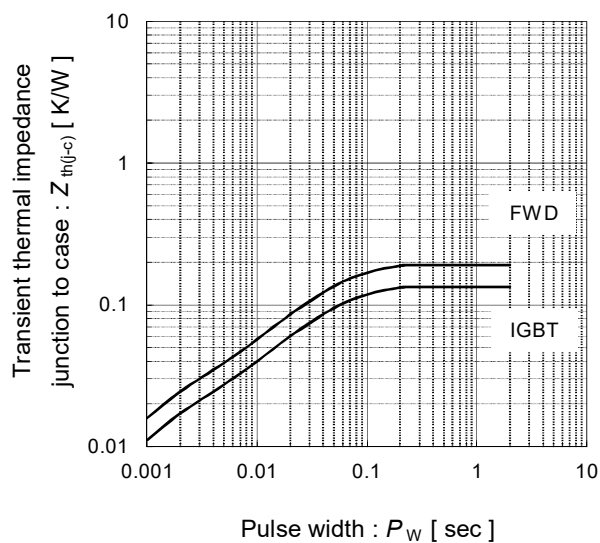
7MBP300XEN065-50

IGBT Modules

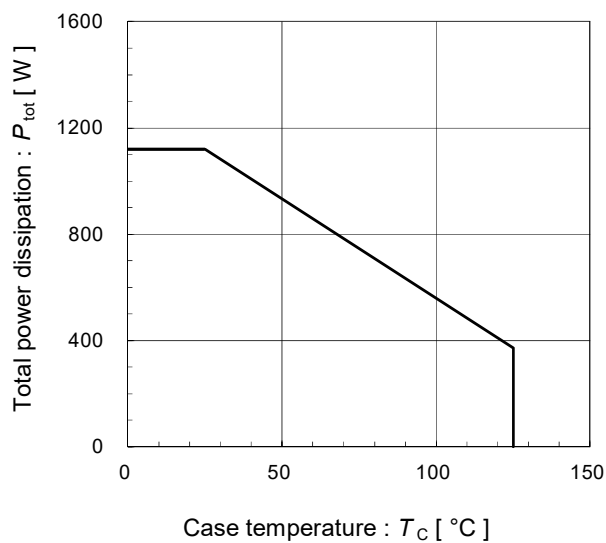
Reversed biased safe operating area (max.)
 $V_{CC}=15V, T_{vj}=150^{\circ}C$



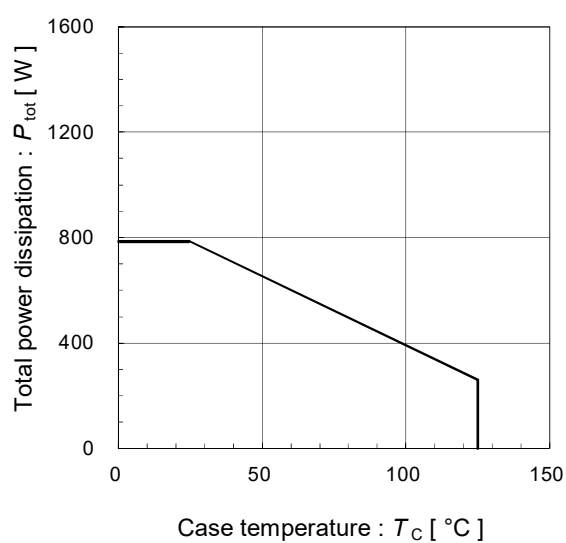
Transient thermal resistance (max.)



Power derating for IGBT (max.)
 [per device]



Power derating for FWD (max.)
 [per device]

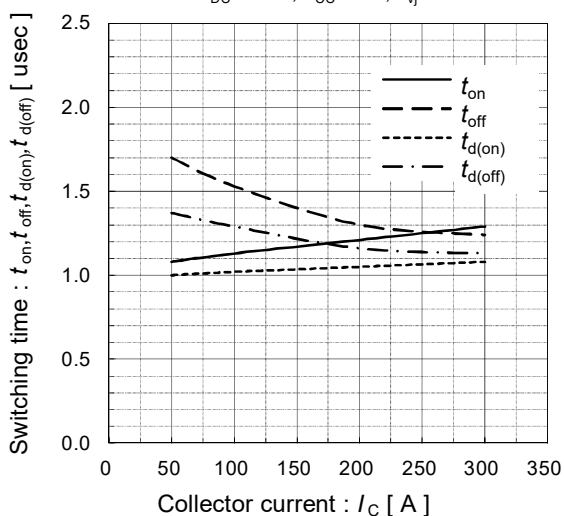


7MBP300XEN065-50

IGBT Modules

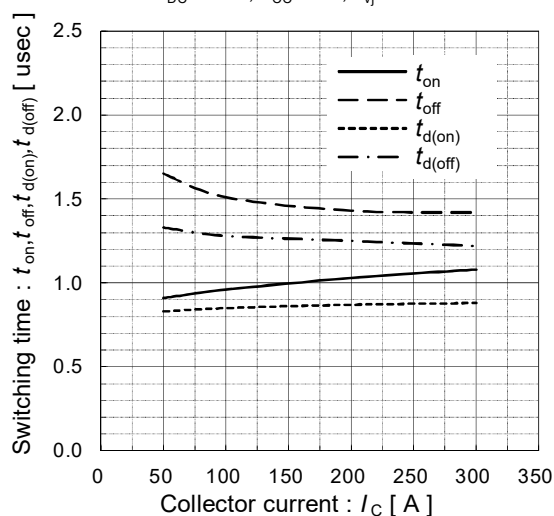
Switching time vs. Collector current (typ.)

$V_{DC}=300V, V_{CC}=15V, T_{vj}=25^{\circ}C$



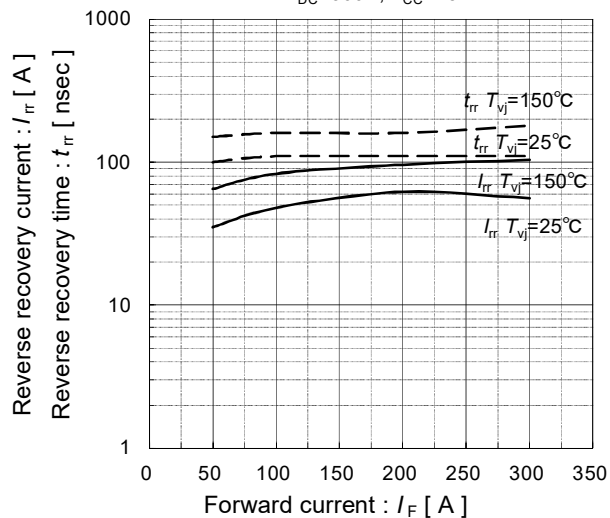
Switching time vs. Collector current (typ.)

$V_{DC}=300V, V_{CC}=15V, T_{vj}=150^{\circ}C$



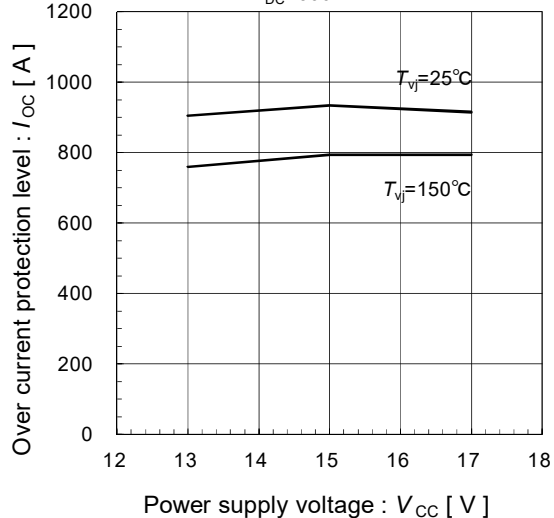
Reverse recovery characteristics (typ.)

$V_{DC}=300V, V_{CC}=15V$



Over current protection vs. Power supply voltage (typ.)

$V_{DC}=300V$

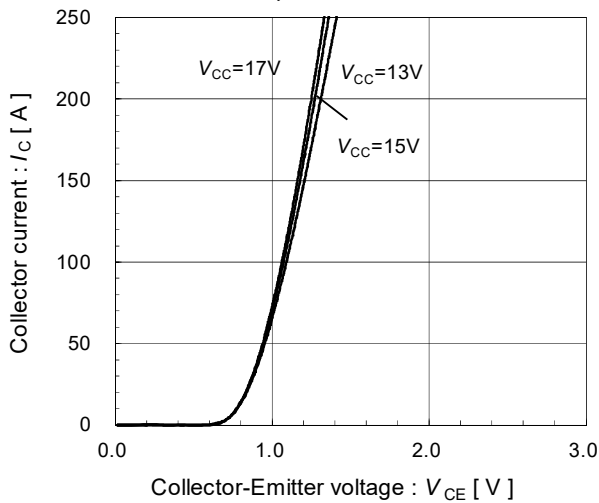


7MBP300XEN065-50

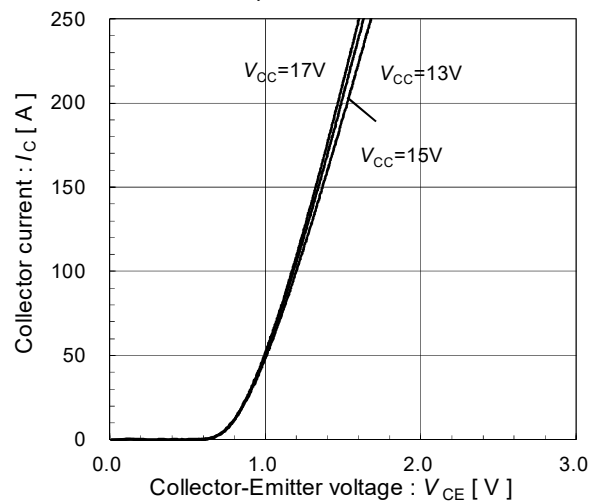
IGBT Modules

● Brake

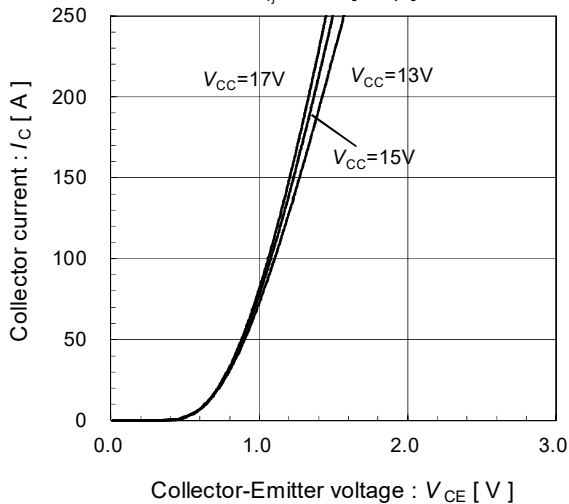
Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=25^{\circ}\text{C}$ [Chip]



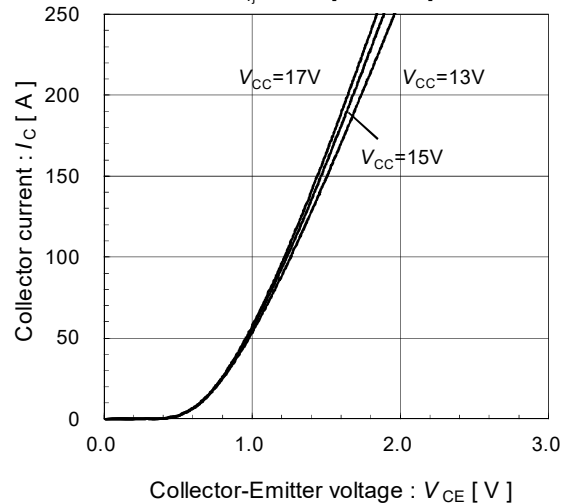
Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=25^{\circ}\text{C}$ [Terminal]



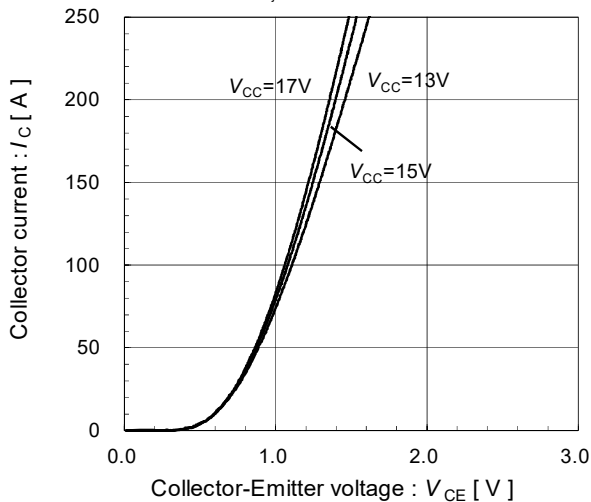
Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=125^{\circ}\text{C}$ [Chip]



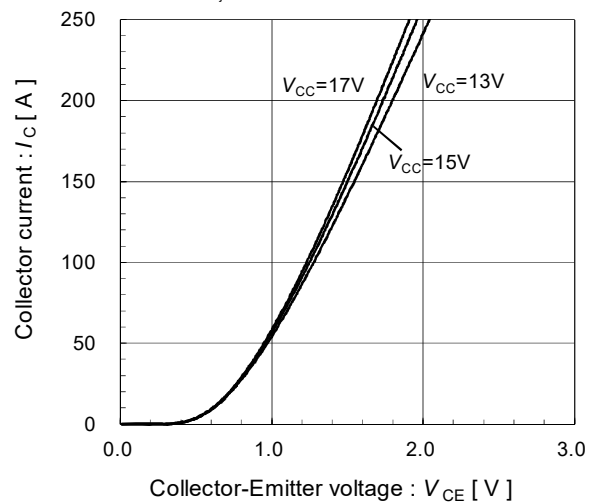
Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=125^{\circ}\text{C}$ [Terminal]



Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=150^{\circ}\text{C}$ [Chip]

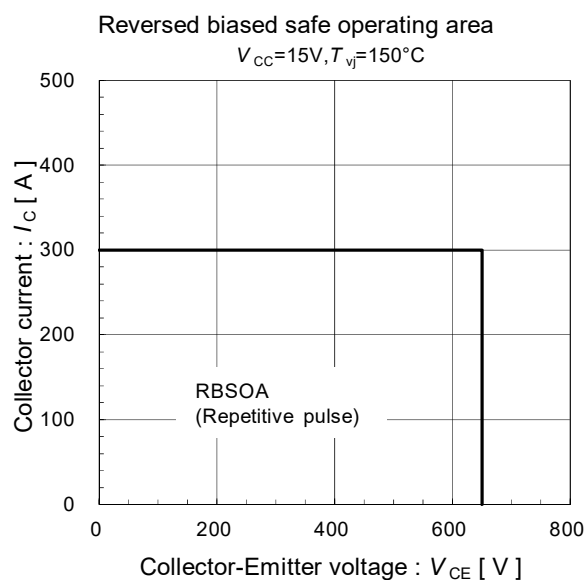
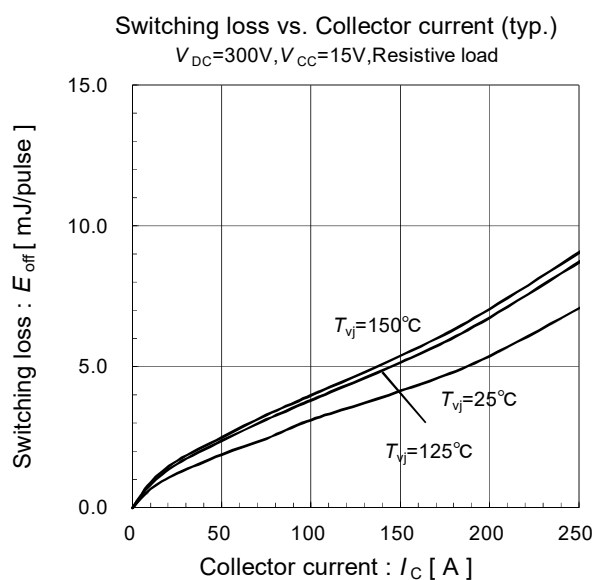
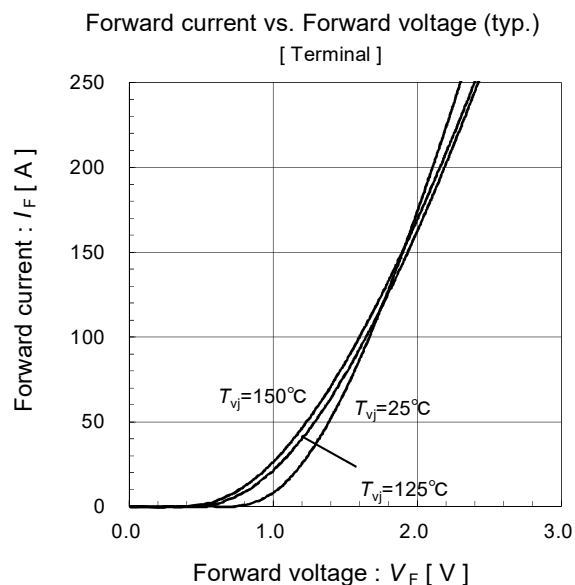
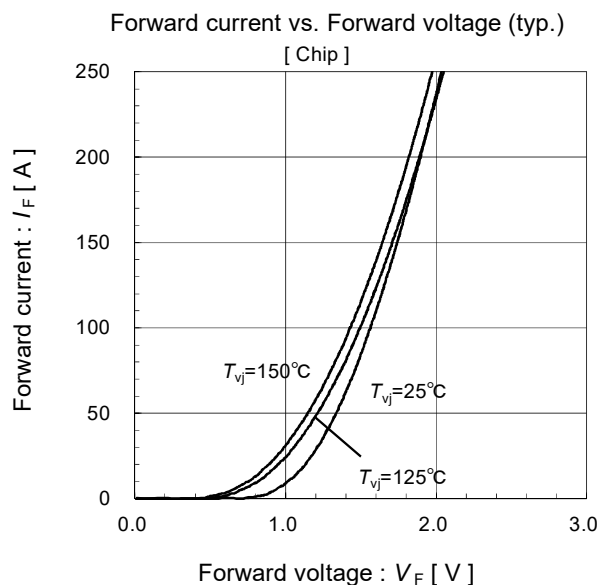


Collector current vs. Collector-Emitter voltage (typ.)
 $T_{vj}=150^{\circ}\text{C}$ [Terminal]



7MBP300XEN065-50

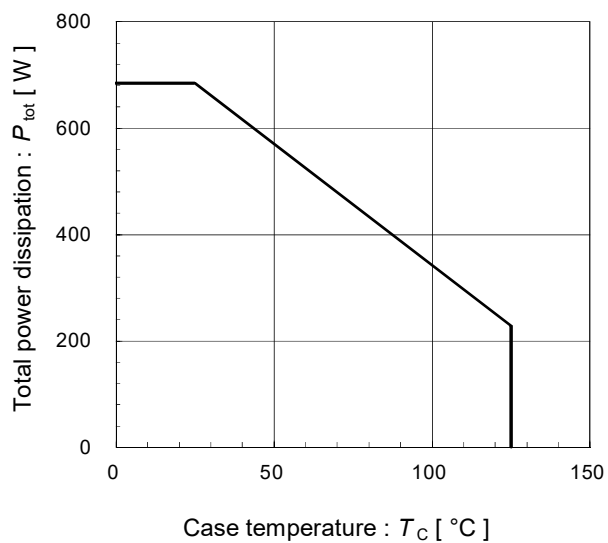
IGBT Modules



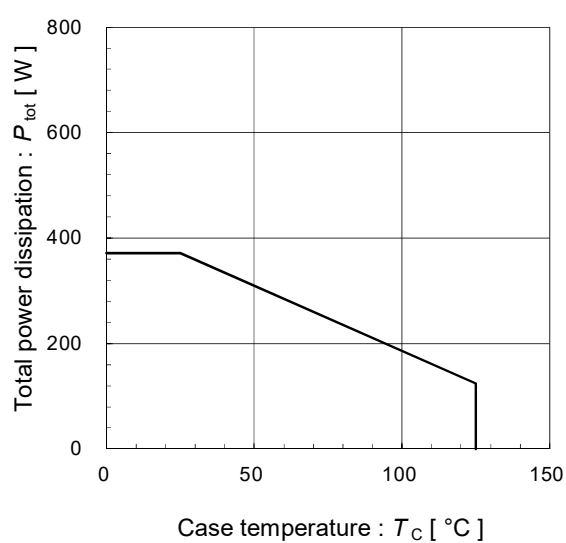
7MBP300XEN065-50

IGBT Modules

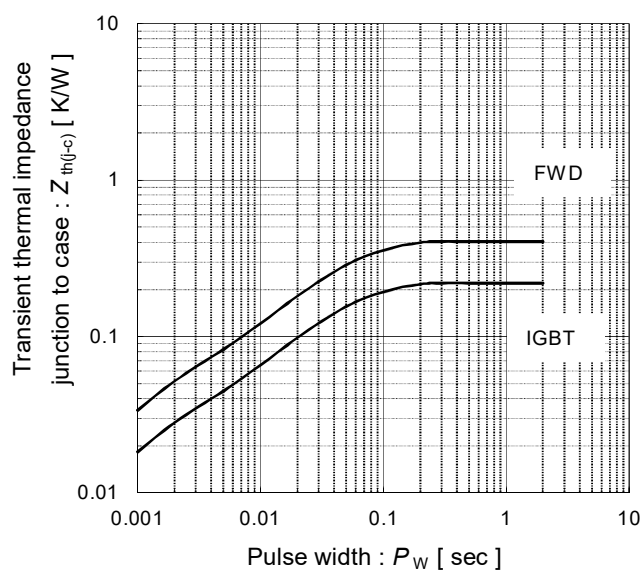
Power derating for IGBT (max.)
[per device]



Power derating for FWD (max.)
[per device]



Transient thermal resistance (max.)



Warnings

1. This Catalog contains the product specifications, characteristics, data, materials, and structures as of 3/2023. The contents are subject to change without notice for specification changes or other reasons. When using a product listed in this Catalog, be sure to obtain the latest specifications.
2. All applications described in this Catalog exemplify the use of Fuji's products for your reference only. No right or license, either express or implied, under any patent, copyright, trade secret or other intellectual property right owned by Fuji Electric Co., Ltd. is (or shall be deemed) granted. Fuji Electric Co., Ltd. makes no representation or warranty, whether express or implied, relating to the infringement or alleged infringement of other's intellectual property rights which may arise from the use of the applications described herein.
3. Although Fuji Electric Co., Ltd. is enhancing product quality and reliability, a small percentage of semiconductor products may become faulty. When using Fuji Electric semiconductor products in your equipment, you are requested to take adequate safety measures to prevent the equipment from causing a physical injury, fire, or other problem if any of the products become faulty. It is recommended to make your design fail-safe, flame retardant, and free of malfunction.
4. The products introduced in this Catalog are intended for use in the following electronic and electrical equipment which has normal reliability requirements.
 · Computers · OA equipment · Communications equipment (terminal devices) · Measurement equipment
 · Machine tools · Audiovisual equipment · Electrical home appliances · Personal equipment · Industrial robots etc.
5. If you need to use a product in this Catalog for equipment requiring higher reliability than normal, such as for the equipment listed below, it is imperative to contact Fuji Electric Co., Ltd. to obtain prior approval. When using these products for such equipment, take adequate measures such as a backup system to prevent the equipment from malfunctioning even if a Fuji's product incorporated in the equipment becomes faulty.
 · Transportation equipment (mounted on cars and ships) · Trunk communications equipment
 · Traffic-signal control equipment · Gas leakage detectors with an auto-shut-off feature
 · Emergency equipment for responding to disasters and anti-burglary devices · Safety devices · Medical equipment
6. Do not use products in this Catalog for the equipment requiring strict reliability such as the following and equivalents to strategic equipment (without limitation).
 · Space equipment · Aeronautic equipment · Nuclear control equipment · Submarine repeater equipment
7. Copyright (c)1996-2023 by Fuji Electric Co., Ltd. All rights reserved.
 No part of this Catalog may be reproduced in any form or by any means without the express permission of Fuji Electric Co., Ltd.
8. If you have any question about any portion in this Catalog, ask Fuji Electric Co., Ltd. or its sales agents before using the product. Neither Fuji Electric Co., Ltd. nor its agents shall be liable for any injury caused by any use of the products not in accordance with instructions set forth herein.

Technical Information

IGBT Modules

- Please refer to URLs below for further information about products, application manuals and design support.
- 关于本规格书中没有记载的产品信息，应用手册，技术信息等，请参考以下链接。
- 本データシートに記載されていない製品情報，アプリケーションマニュアル，デザインサポートは以下の URL をご参照下さい。

FUJI ELECTRIC Power Semiconductor WEB site

日本	www.fujielectric.co.jp/products/semiconductor/
Global	www.fujielectric.com/products/semiconductor/
中国	www.fujielectric.com.cn/products/semiconductor/
Europe	www.fujielectric-europe.com/en/power_semiconductor/
North America	www.americas.fujielectric.com/products/semiconductors/

Information

日本

1 半導体総合カタログ	www.fujielectric.co.jp/products/semiconductor/catalog/
2 製品情報	www.fujielectric.co.jp/products/semiconductor/model/
3 アプリケーションマニュアル	www.fujielectric.co.jp/products/semiconductor/model/igbt/application/
4 デザインサポート	www.fujielectric.co.jp/products/semiconductor/model/igbt/technical/
5 マウンティングインストラクション	www.fujielectric.co.jp/products/semiconductor/model/igbt/mounting/
6 IGBT 損失シミュレーションソフト	www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation/
7 富士電機技報	www.fujielectric.co.jp/products/semiconductor/journal/
8 製品のお問い合わせ	www.fujielectric.co.jp/products/semiconductor/contact/
9 改廃のお知らせ	www.fujielectric.co.jp/products/semiconductor/discontinued/

Global

1 Semiconductors General Catalog	www.fujielectric.com/products/semiconductor/catalog/
2 Product Information	www.fujielectric.com/products/semiconductor/model/
3 Application Manuals	www.fujielectric.com/products/semiconductor/model/igbt/application/
4 Design Support	www.fujielectric.com/products/semiconductor/model/igbt/technical/
5 Mounting Instructions	www.fujielectric.com/products/semiconductor/model/igbt/mounting/
6 IGBT Loss Simulation Software	www.fujielectric.com/products/semiconductor/model/igbt/simulation/
7 Fuji Electric Journal	www.fujielectric.com/products/semiconductor/journal/
8 Contact	www.fujielectric.com/contact/
9 Revised and discontinued product information	www.fujielectric.com/products/semiconductor/discontinued/

中国

1 半导体综合目录	www.fujielectric.com.cn/products/semiconductor/catalog/
2 产品信息	www.fujielectric.com.cn/products/semiconductor/model/
3 应用手册	www.fujielectric.com.cn/products/semiconductor/model/igbt/application/
4 技术信息	www.fujielectric.com.cn/products/semiconductor/model/igbt/technical/
5 安装说明书	www.fujielectric.com.cn/products/semiconductor/model/igbt/mounting/
6 IGBT 损耗模拟软件	www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/
7 富士电机技报	www.fujielectric.com.cn/products/semiconductor/journal/
8 产品咨询	www.fujielectric.com/contact/
9 产品更改和停产信息	www.fujielectric.com.cn/products/semiconductor/discontinued/